# mail

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

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# MBRH200150 thru MBRH200200R

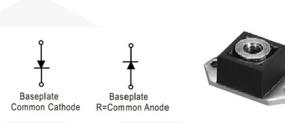
D-67 Package

### Silicon Power Schottky Diode

#### V<sub>RRM</sub> = 150 V - 200 V I<sub>F(AV)</sub> = 200 A

#### Features

- High Surge Capability
- Types from 150 V to 200 V  $V_{\text{RRM}}$
- Not ESD Sensitive





#### Maximum ratings, at T<sub>j</sub> = 25 °C, unless otherwise specified ("R" devices have leads reversed)

Parameter	Symbol	Conditions	MBRH200150(R)		MBRH200200(R)	Unit
Repetitive peak reverse voltage	V <sub>RRM</sub>		150		200	V
RMS reverse voltage	V <sub>RMS</sub>		106		141	V
DC blocking voltage	V <sub>DC</sub>		150		150	V
Operating temperature	Tj		-55 to 150		-55 to 150	°C
Storage temperature	T <sub>stg</sub>		-55 to 150	/	-55 to 150	C°

#### Electrical characteristics, at Tj = 25 °C, unless otherwise specified

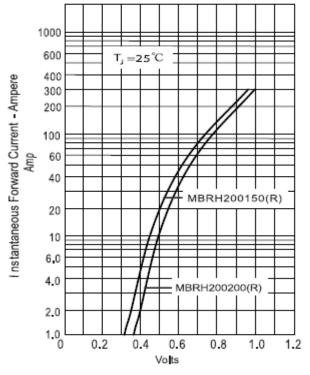
Parameter	Symbol	Conditions	MBRH200150(R)	MBRH200200(R)	Unit
Average forward current (per pkg)	I <sub>F(AV)</sub>	T <sub>C</sub> = 125 °C	200	200	А
Peak forward surge current	I <sub>FSM</sub>	$t_p$ = 8.3 ms, half sine	3000	3000	А
Maximum instantaneous forward voltage	$V_{F}$	I <sub>FM</sub> = 200 A, T <sub>j</sub> = 25 °C	0.88	0.92	V
Maximum instantaneous		T <sub>j</sub> = 25 °C	1	1	mA
reverse current at rated DC	I <sub>R</sub>	T <sub>j</sub> = 100 °C	10	10	
blocking voltage		T <sub>j</sub> = 150 °C	50	50	
Thermal characteristics					
Thermal resistance, junction-	$R_{\Theta JC}$		0.35	0.35	°C/W
case					





# MBRH200150 thru MBRH200200R

Figure .1- Typical Forward Characteristics



nstantaneous Forward Voltage - Volts

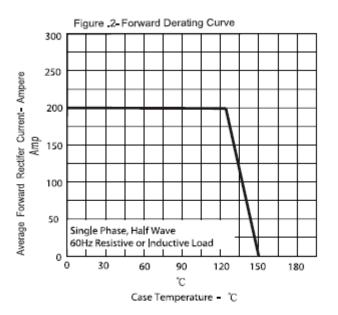
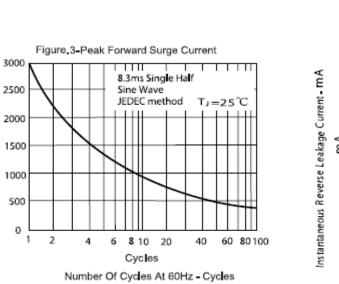
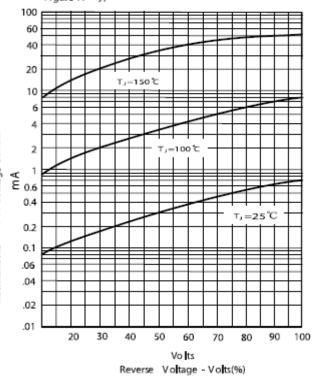


Figure .4- Typical Reverse Characteristics





Peak Forward Surge Current-Ampere

Amp



# MBRH200150 thru MBRH200200R

#### Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.

